

View Online at <https://aerobasegroup.com/nsn/5961-01-087-7226>

Inclosure Material:

Metal

Overall Length:

0.165 inches

Overall Diameter:

0.200 inches

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage, dc all transistor and 30.0 collector to emitter voltage, dc all transistor and 5.0 emitter to base voltage, dc all transistor

Current Rating Per Characteristic:

500.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

1.6 watts small-signal input power, common-collector preset all transistor

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

All transistor junction pattern arrangement: npn

Test Data Document:

97942-581r870 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

6 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fig:

A110a0